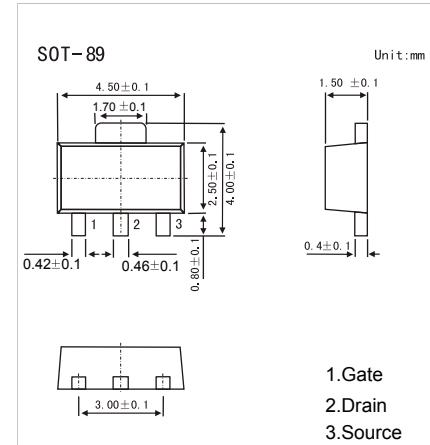


P-Channel MOSFET

2SJ287

■ Features

- $V_{DS} (V) = -30V$
- $I_D = -500mA$
- $R_{DS(ON)} < 2.2\Omega$ ($V_{GS} = -10V$)
- $R_{DS(ON)} < 3.3\Omega$ ($V_{GS} = -4V$)

■ Absolute Maximum Ratings $T_a = 25^\circ C$

| Parameter | Symbol | Rating | Unit |
|---|-----------|------------|------------|
| Drain-Source Voltage | V_{DS} | -30 | V |
| Gate-Source Voltage | V_{GS} | ± 15 | |
| Continuous Drain Current | I_D | -0.5 | A |
| Pulsed Drain Current (Note.1) | I_{DM} | -2 | |
| Power Dissipation $T_c = 25^\circ C$ | P_D | 3.5 | W |
| | | 1.3 | |
| Junction Temperature | T_J | 150 | $^\circ C$ |
| Junction Storage Temperature Range | T_{stg} | -55 to 150 | |

Note.1: PW ≤ 10ms, Duty Cycle ≤ 50%

■ Electrical Characteristics $T_a = 25^\circ C$

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|-----------------------------------|---------------|--|-----|-----|----------|----------|
| Drain-Source Breakdown Voltage | V_{DSS} | $I_D = -1mA, V_{GS} = 0V$ | -30 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -30V, V_{GS} = 0V$ | | | -100 | uA |
| Gate-Body leakage current | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 12V$ | | | ± 10 | uA |
| Gate Cut off Voltage | $V_{GS(off)}$ | $V_{DS} = -10V, I_D = -1mA$ | -1 | | -2 | V |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS} = -10V, I_D = -250mA$ | | | 2.2 | Ω |
| | | $V_{GS} = -4V, I_D = -250mA$ | | | 3.3 | |
| Forward Transconductance | g_{FS} | $V_{DS} = -10V, I_D = -250mA$ | 240 | 400 | | mS |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = -10V, f = 1MHz$ | | 50 | | pF |
| Output Capacitance | C_{oss} | | | 35 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 10 | | |
| Turn-On Delay Time | $t_{d(on)}$ | | | 7 | | ns |
| Turn-On Rise Time | t_r | | | 10 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 35 | | |
| Turn-Off Fall Time | t_f | | | 20 | | |
| Diode Forward Voltage | V_{SD} | $I_S = -0.5A, V_{GS} = 0V$ | | -1 | | V |

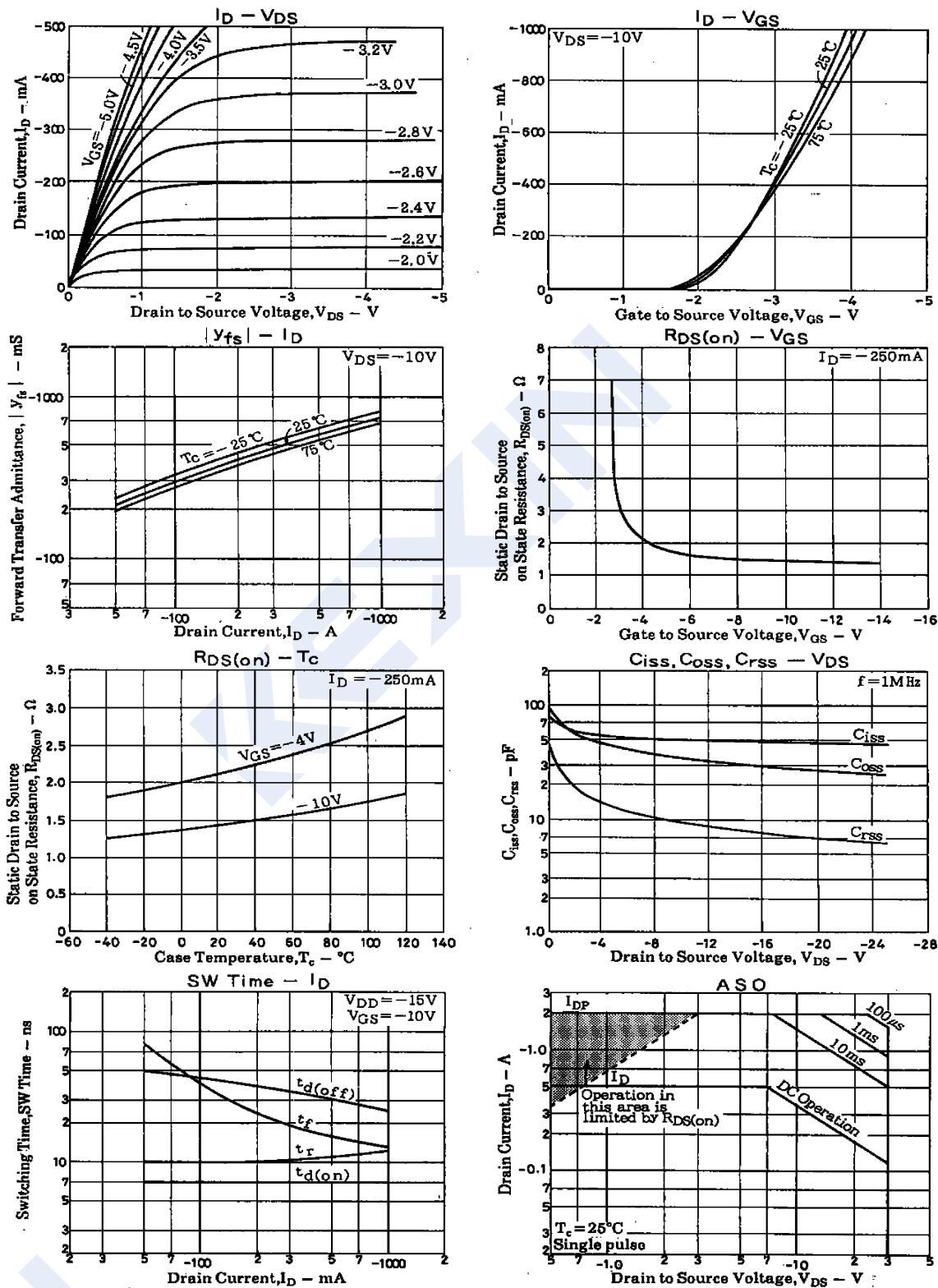
■ Marking

| | |
|---------|----|
| Marking | JD |
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P-Channel MOSFET

2SJ287

■ Typical Characteristics



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■ Typical Characteristics

